

## High and Low Side Driver

### Features

- Floating channel designed for bootstrap operation
- Fully operational to 200V
- Tolerant to negative transient voltage, dV/dt immune
- Gate drive supply range from 10 to 20V
- Independent low and high side channels
- Input logic HIN/LIN active high
- Undervoltage lockout for both channels
- 3.3V and 5V logic compatible
- CMOS Schmitt-triggered inputs with pull-down
- Matched propagation delay for both channels

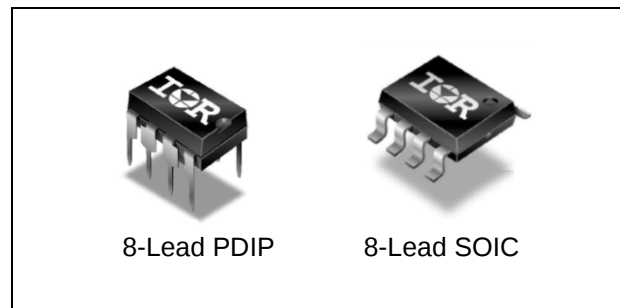
### Product Summary

|                           |             |
|---------------------------|-------------|
| $V_{\text{OFFSET}}$ (max) | 200V        |
| $I_{\text{O+/-}}$ (typ)   | 1.0A / 1.0A |
| $V_{\text{OUT}}$          | 10 – 20V    |
| $t_{\text{on/off}}$ (typ) | 60ns        |
| Delay Matching (max)      | 20ns        |

### Description

The IRS2011 is a high power, high speed power MOSFET driver with independent high and low side referenced output channels. Logic inputs are compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Propagation delays are matched to simplify use in high frequency applications. The floating channel can be used to drive an N-channel power MOSFET in the high side configuration which operates up to 200 volts. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction.

### Package Options



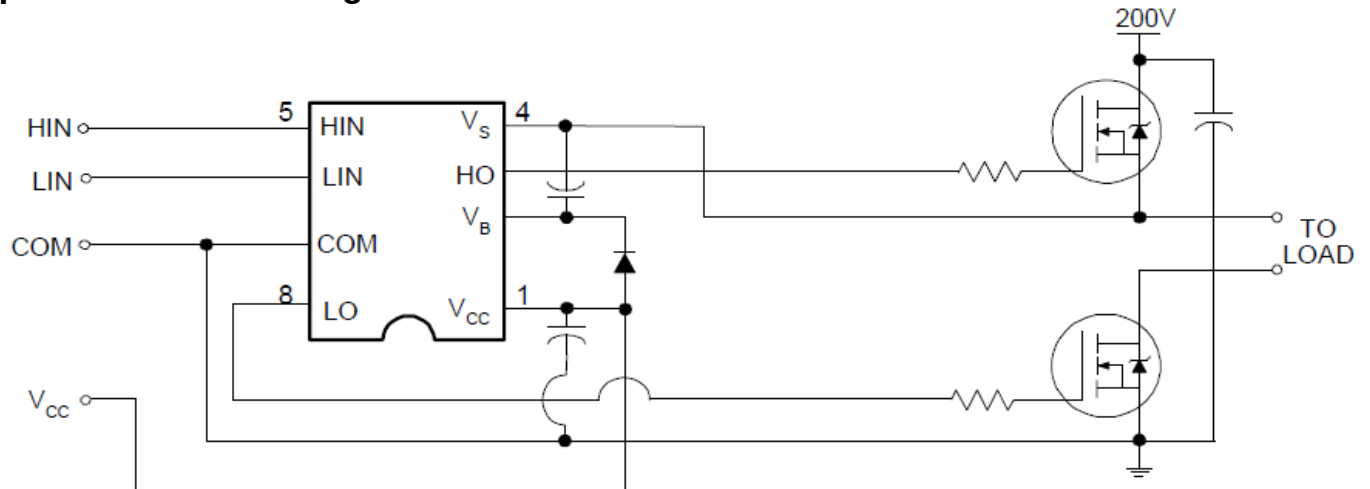
### Applications

- Converters
- DC motor drive

### Ordering Information

| Base Part Number | Package Type | Standard Pack |          | Orderable Part Number |
|------------------|--------------|---------------|----------|-----------------------|
|                  |              | Form          | Quantity |                       |
| IRS2011PBF       | PDIP8        | Tube          | 50       | IRS2011PBF            |
| IRS2011SPBF      | SO8N         | Tube          | 95       | IRS2011SPBF           |
| IRS2011SPBF      | SO8N         | Tape and Reel | 2500     | IRS2011STRPBF         |

## Typical Connection Diagram



(Refer to Lead Assignments for correct configuration.) This diagram shows electrical connections only. Please refer to our Application Notes and Design Tips for proper circuit board layout.

## Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

| Symbol              | Definition                                            |             | Min.                 | Max.                  | Units |
|---------------------|-------------------------------------------------------|-------------|----------------------|-----------------------|-------|
| V <sub>B</sub>      | High side floating supply voltage                     |             | -0.3                 | 220 <sup>†</sup>      | V     |
| V <sub>S</sub>      | High side floating supply offset voltage              |             | V <sub>B</sub> - 20  | V <sub>B</sub> + 0.3  |       |
| V <sub>HO</sub>     | High side floating output voltage                     |             | V <sub>S</sub> - 0.3 | V <sub>B</sub> + 0.3  |       |
| V <sub>CC</sub>     | Low side fixed supply voltage                         |             | -0.3                 | 20 <sup>†</sup>       |       |
| V <sub>LO</sub>     | Low side output voltage                               |             | -0.3                 | V <sub>CC</sub> + 0.3 |       |
| V <sub>IN</sub>     | Logic input voltage (HIN, LIN)                        |             | -0.3                 | V <sub>CC</sub> + 0.3 |       |
| dV <sub>S</sub> /dt | Allowable offset supply voltage transient             |             | —                    | 50                    | V/ns  |
| P <sub>D</sub>      | Package power dissipation<br>@ T <sub>A</sub> ≤ +25°C | 8-Lead PDIP | —                    | 1.0                   | W     |
|                     |                                                       | 8-Lead SOIC | —                    | 0.625                 |       |
| R <sub>thJA</sub>   | Thermal resistance, junction to ambient               | 8-Lead PDIP | —                    | 125                   | °C/W  |
|                     |                                                       | 8-Lead SOIC | —                    | 200                   |       |
| T <sub>J</sub>      | Junction temperature                                  |             | —                    | 150                   | °C    |
| T <sub>S</sub>      | Storage temperature                                   |             | -55                  | 150                   |       |
| T <sub>L</sub>      | Lead temperature (soldering, 10 seconds)              |             | —                    | 300                   |       |

† All supplies are fully tested at 25V and an internal 20V clamp exists for each supply

## Recommended Operating Conditions

For proper operation the device should be used within the recommended conditions. The  $V_S$  and COM offset ratings are tested with all supplies biased at 15V differential.

| Symbol   | Definition                                 | Min.       | Max.       | Units            |
|----------|--------------------------------------------|------------|------------|------------------|
| $V_B$    | High side floating supply absolute voltage | $V_S + 10$ | $V_S + 20$ | V                |
| $V_S$    | High side floating supply offset voltage   | ††         | 200        |                  |
| $V_{HO}$ | High side floating output voltage          | $V_S$      | $V_B$      |                  |
| $V_{CC}$ | Low side fixed supply voltage              | 10         | 20         |                  |
| $V_{LO}$ | Low side output voltage                    | 0          | $V_{CC}$   |                  |
| $V_{IN}$ | Logic input voltage (HIN, LIN)             | COM        | $V_{CC}$   |                  |
| $T_A$    | Ambient temperature                        | -40        | 125        | $^\circ\text{C}$ |

†† Logic operational for  $V_S$  of -5 to +200V. Logic state held for  $V_S$  of -5V to  $-V_{BS}$ .

## Dynamic Electrical Characteristics

$V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ) = 15V,  $C_L$  = 1000pF and  $T_A$  = 25°C unless otherwise specified. Figure 1 shows the timing definitions.

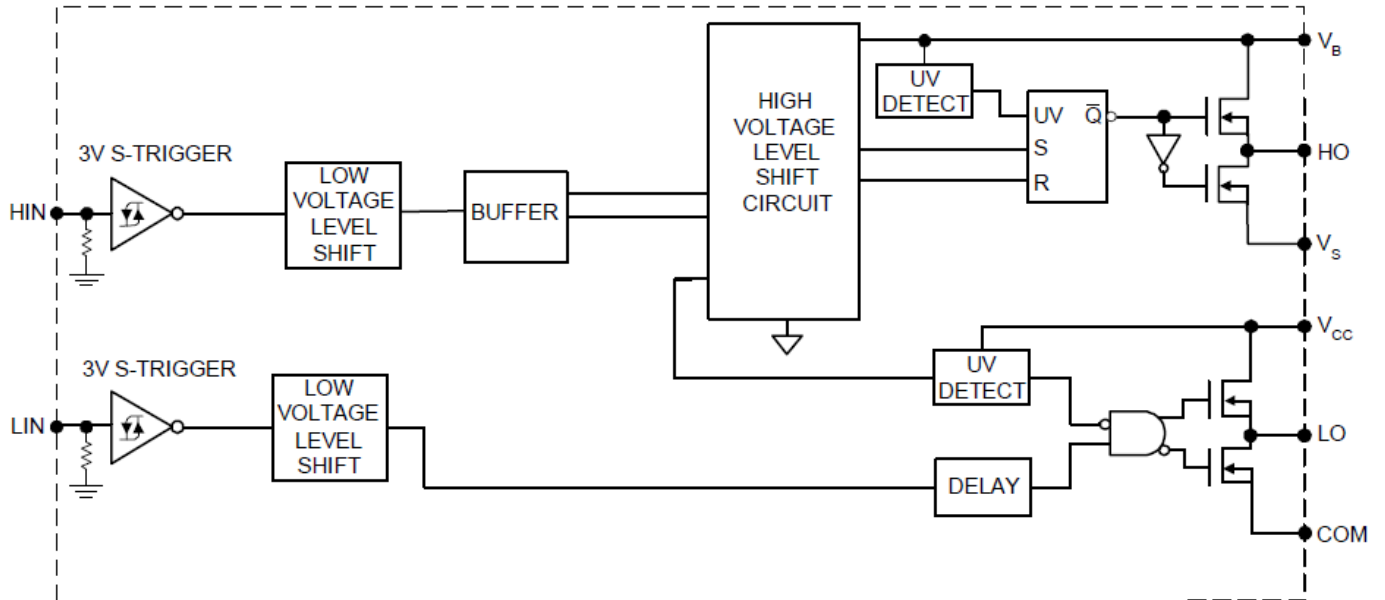
| Symbol    | Definition                                             | Min. | Typ. | Max. | Units | Test Conditions |
|-----------|--------------------------------------------------------|------|------|------|-------|-----------------|
| $t_{on}$  | Turn-on propagation delay                              | —    | 60   | 80   | ns    | $V_S = 0V$      |
| $t_{off}$ | Turn-off propagation delay                             | —    | 60   | 80   |       | $V_S = 200V$    |
| $t_r$     | Turn-on rise time                                      | —    | 25   | 40   |       |                 |
| $t_f$     | Turn-off fall time                                     | —    | 15   | 35   |       |                 |
| DM1       | Turn-on delay matching<br>  $t_{on}(H) - t_{on}(L)$    | —    | —    | 20   |       |                 |
| DM2       | Turn-off delay matching<br>  $t_{off}(H) - t_{off}(L)$ | —    | —    | 20   |       |                 |

## Static Electrical Characteristics

$V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ) = 15V and  $T_A$  = 25°C unless otherwise specified. The  $V_{IN}$ ,  $V_{TH}$  and  $I_{IN}$  parameters are referenced to COM and are applicable to all logic input leads: HIN and LIN. The  $V_O$  and  $I_O$  parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

| Symbol      | Definition                                            | Min. | Typ. | Max. | Units   | Test Conditions                    |
|-------------|-------------------------------------------------------|------|------|------|---------|------------------------------------|
| $V_{IH}$    | Logic "1" input voltage                               | 2.5  | —    | —    | V       | $V_{CC} = 10V - 20V$               |
| $V_{IL}$    | Logic "0" input voltage                               | —    | —    | 0.7  |         |                                    |
| $V_{OH}$    | High level output voltage, $V_{BIAS} - V_O$           | —    | —    | 1.4  |         | $I_O = 0A$                         |
| $V_{OL}$    | Low level output voltage, $V_O$                       | —    | —    | 0.1  |         | $I_O = 20mA$                       |
| $I_{LK}$    | Offset supply leakage current                         | —    | —    | 50   | $\mu A$ | $V_B = V_S = 200V$                 |
| $I_{QBS}$   | Quiescent $V_{BS}$ supply current                     | —    | 120  | 210  |         | $V_{IN} = 0V$ or 3.3V              |
| $I_{QCC}$   | Quiescent $V_{CC}$ supply current                     | —    | 200  | 300  |         |                                    |
| $I_{IN+}$   | Logic "1" input bias current                          | —    | 3    | 10   |         | $V_{IN} = 3.3V$                    |
| $I_{IN-}$   | Logic "0" input bias current                          | —    | —    | 5    |         | $V_{IN} = 0V$                      |
| $V_{BSUV+}$ | $V_{BS}$ supply undervoltage positive going threshold | 8.3  | 9.0  | 9.7  | V       |                                    |
| $V_{BSUV-}$ | $V_{BS}$ supply undervoltage negative going threshold | 7.5  | 8.2  | 8.9  |         |                                    |
| $V_{CCUV+}$ | $V_{CC}$ supply undervoltage positive going threshold | 8.3  | 9.0  | 9.7  |         |                                    |
| $V_{CCUV-}$ | $V_{CC}$ supply undervoltage negative going threshold | 7.5  | 8.2  | 8.9  |         |                                    |
| $I_{O+}$    | Output high short circuit pulsed current              | —    | 1.0  | —    | A       | $V_O = 0V$ ,<br>$PW \leq 10 \mu s$ |
| $I_{O-}$    | Output low short circuit pulsed current               | —    | 1.0  | —    |         | $V_O = 15V$<br>$PW \leq 10 \mu s$  |

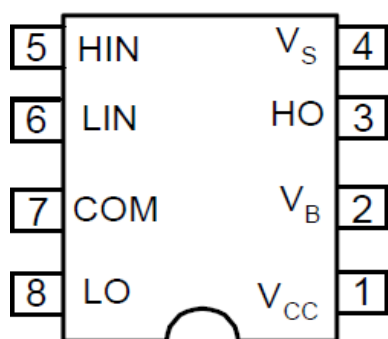
## Functional Block Diagram



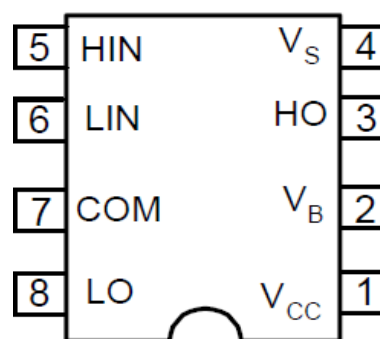
## Lead Definitions

| Symbol   | Description                                                  |
|----------|--------------------------------------------------------------|
| HIN      | Logic input for high side gate driver outputs (HO), in phase |
| LIN      | Logic input for low side gate driver outputs (LO), in phase  |
| $V_B$    | High side floating supply                                    |
| HO       | High side gate drive output                                  |
| $V_S$    | High side floating supply return                             |
| $V_{CC}$ | Low side supply                                              |
| LO       | Low side gate drive output                                   |
| COM      | Low side return                                              |

## Lead Assignments

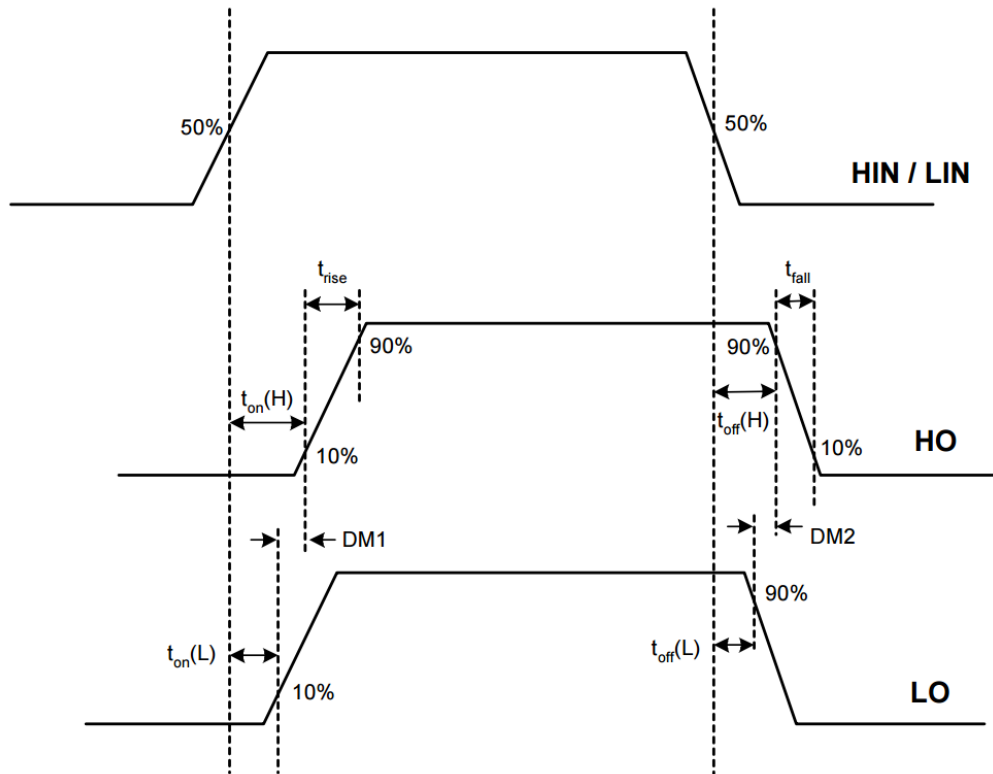


**8-Lead PDIP**

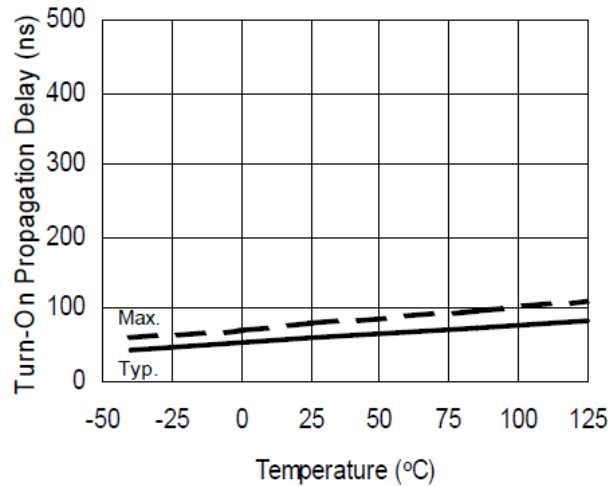


**8-Lead SOIC**

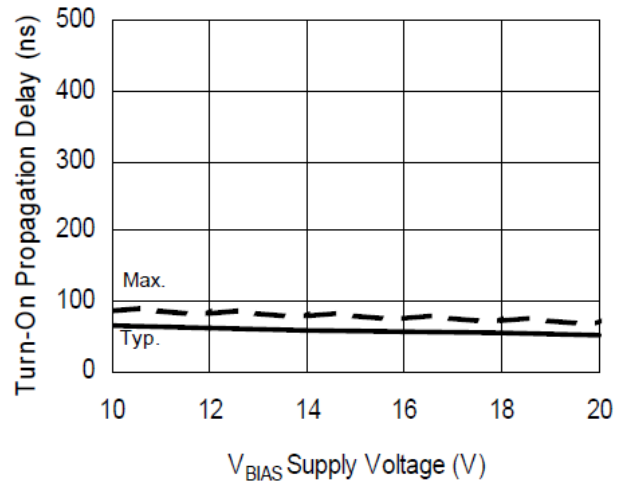
## Application Information and Additional Details



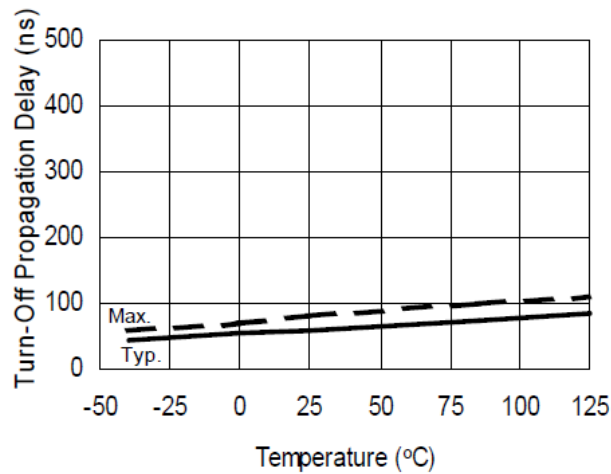
**Figure 1. Timing Diagram**



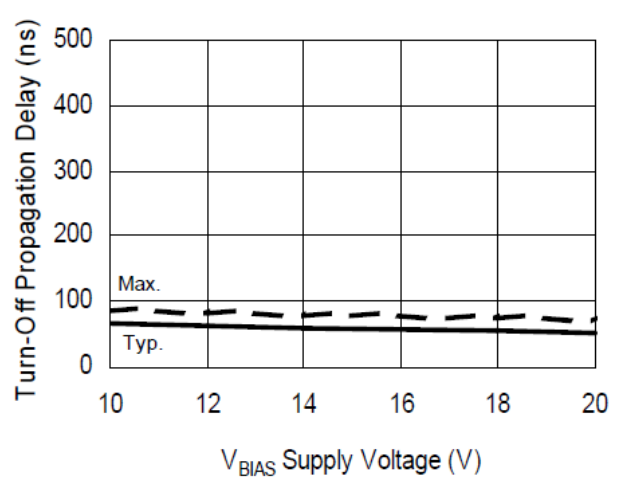
**Figure 2A. Turn-on Propagation Delay vs. Temperature**



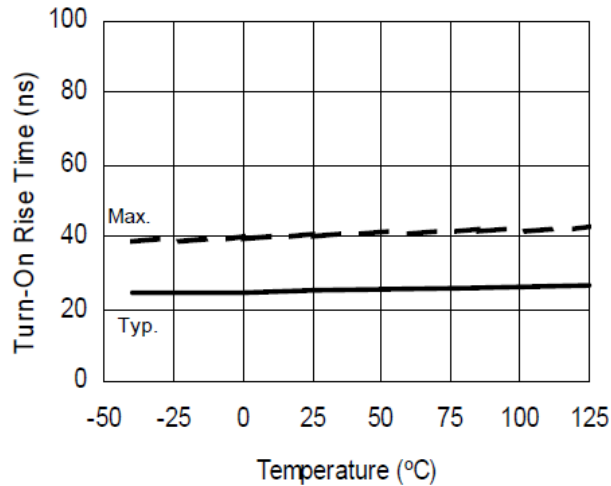
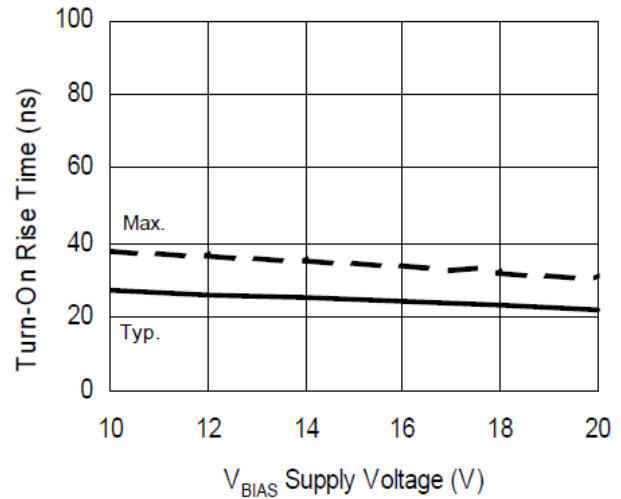
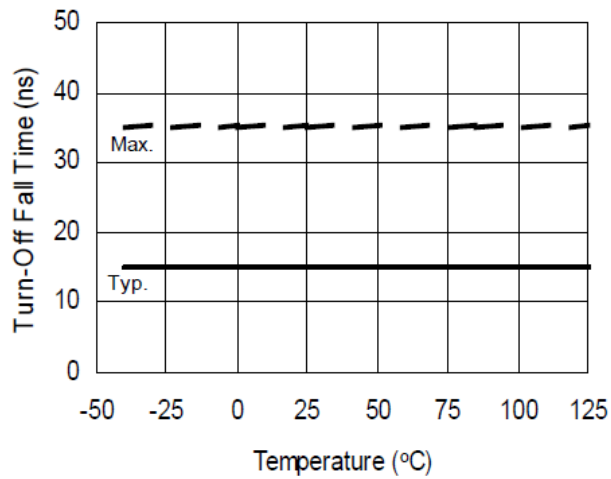
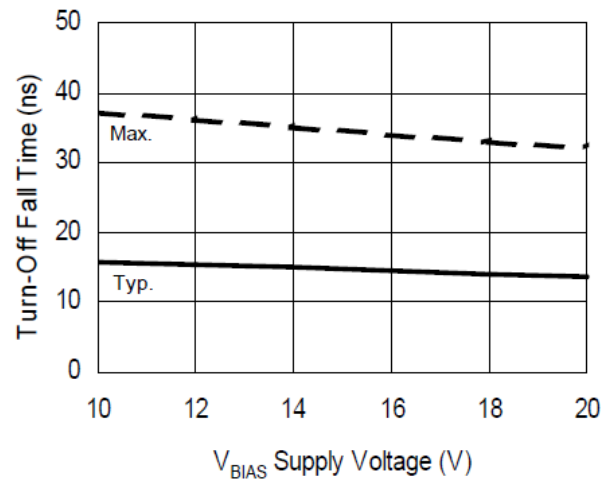
**Figure 2B. Turn-on Propagation Delay vs. Supply Voltage**

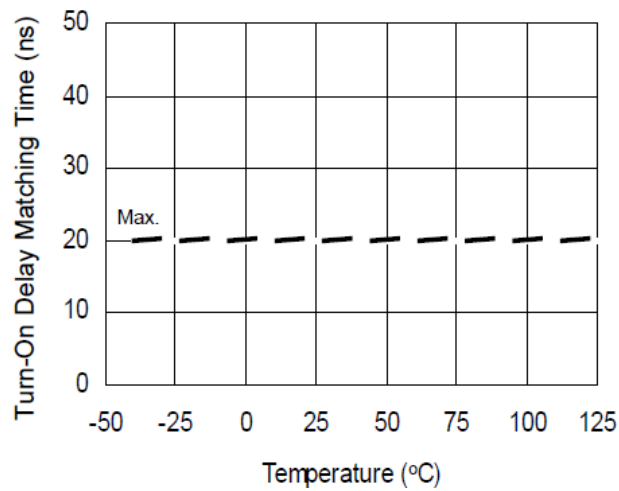


**Figure 3A. Turn-off Propagation Delay vs. Temperature**

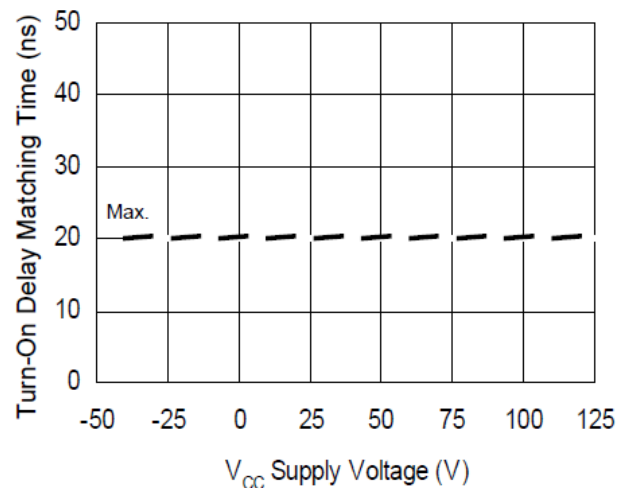


**Figure 3B. Turn-off Propagation Delay vs. Supply Voltage**

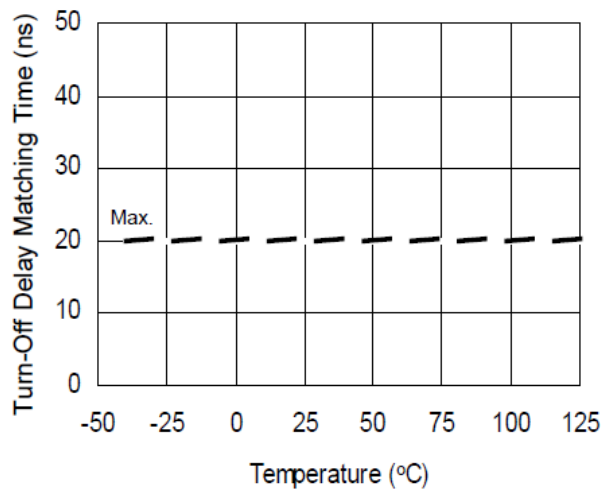

**Figure 4A. Turn-on Rise Time vs. Temperature**

**Figure 4B. Turn-on Rise Time vs. Supply Voltage**

**Figure 5A. Turn-off Fall Time vs. Temperature**

**Figure 5B. Turn-off Fall Time vs. Supply Voltage**



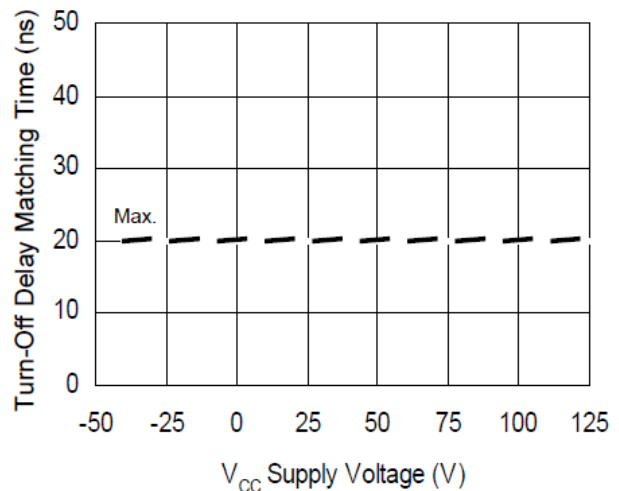
**Figure 6A. Turn-on Delay Matching Time vs. Temperature**



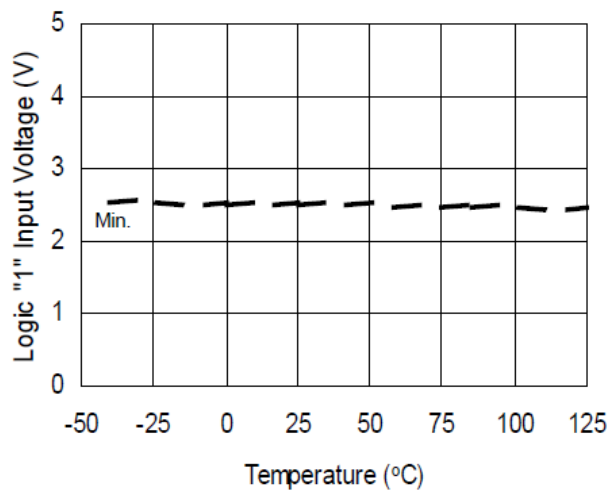
**Figure 6B. Turn-on Delay Matching Time vs. Supply Voltage**



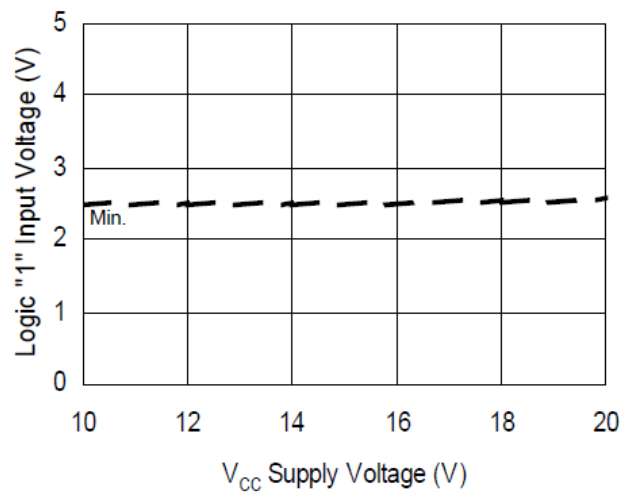
**Figure 7A Turn-off Delay Matching Time vs. Temperature**



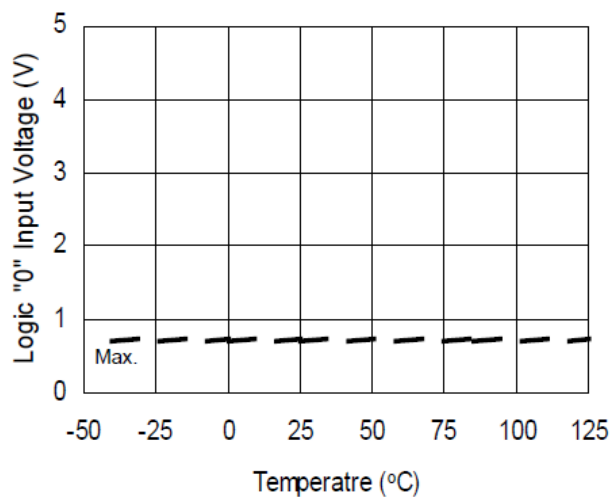
**Figure 7B. Turn-off Delay Matching Time vs. Supply Voltage**



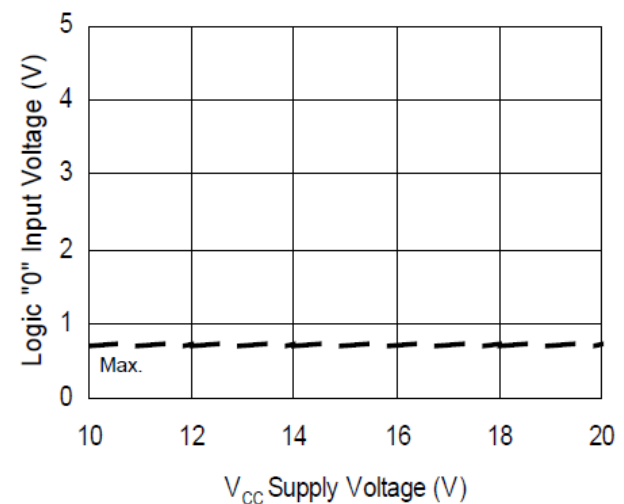
**Figure 8A. Logic "1" Input Voltage vs. Temperature**



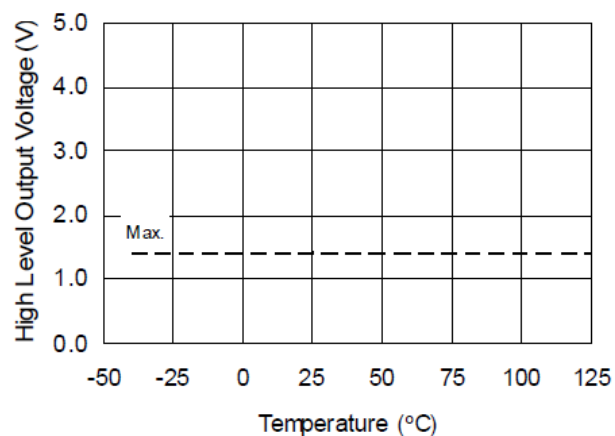
**Figure 8B. Logic "1" Input Voltage vs. Supply Voltage**



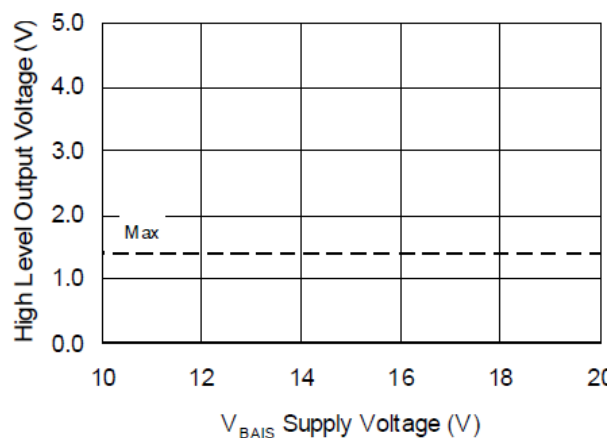
**Figure 9A. Logic "0" Input Voltage vs. Temperature**



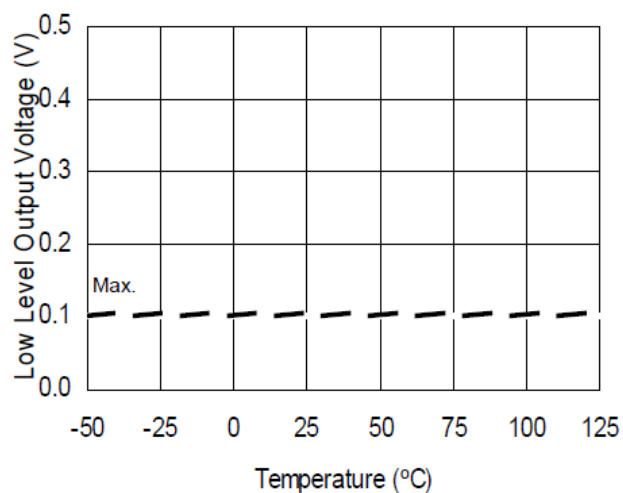
**Figure 9B. Logic "0" Input Voltage vs. Supply Voltage**



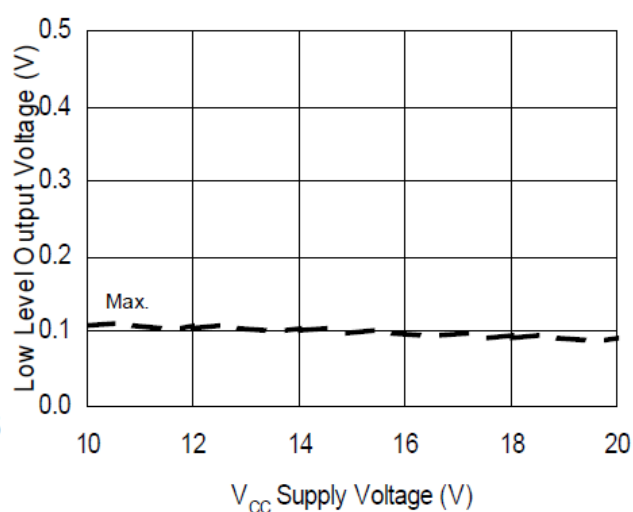
**Figure 10A. High Level Output Voltage vs. Temperature ( $I_o = 0\text{mA}$ )**



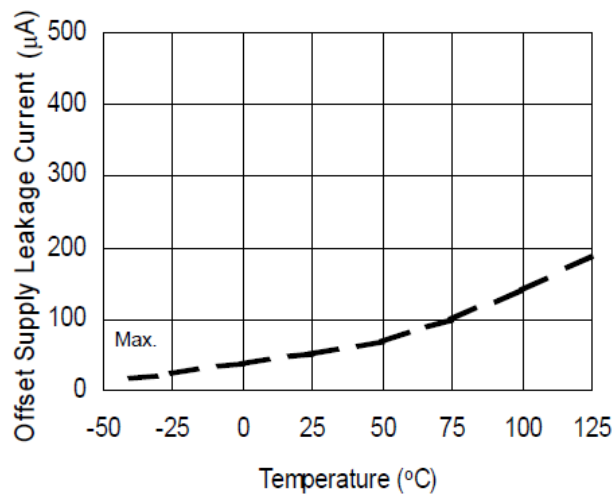
**Figure 10B. High Level Output Voltage vs. Supply Voltage ( $I_o = 0\text{mA}$ )**



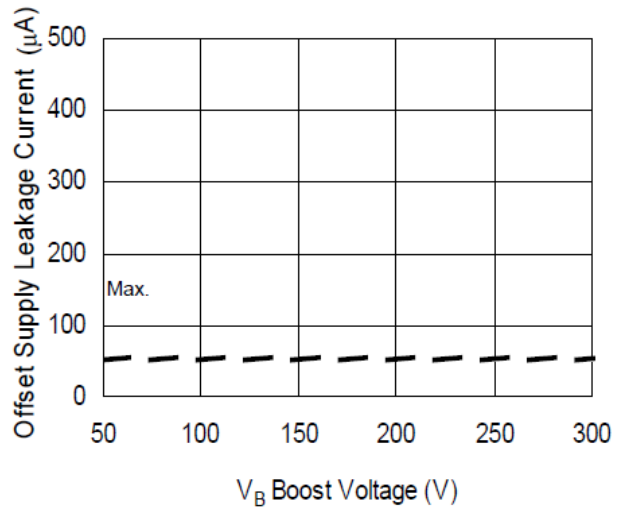
**Figure 11A. Low Level Output Voltage vs. Temperature**



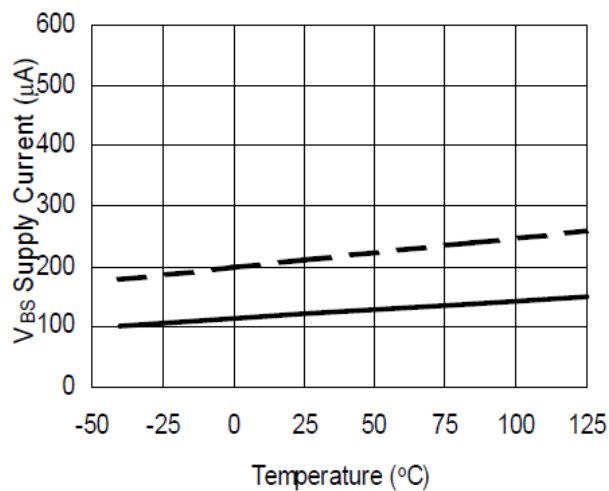
**Figure 11B. Low Level Output vs. Supply Voltage**



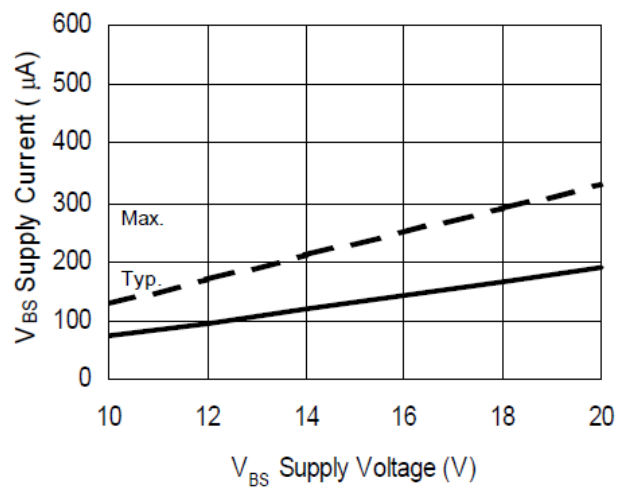
**Figure 12A. Offset Supply Leakage Current vs. Temperature**



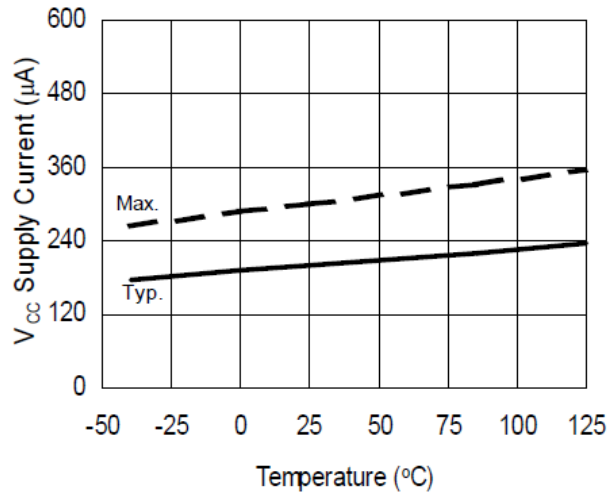
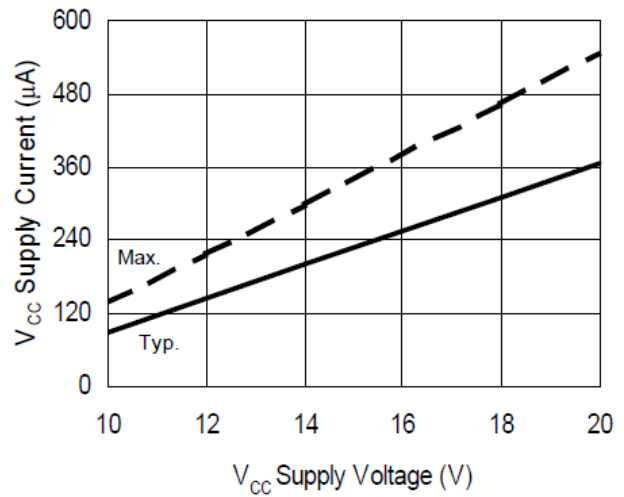
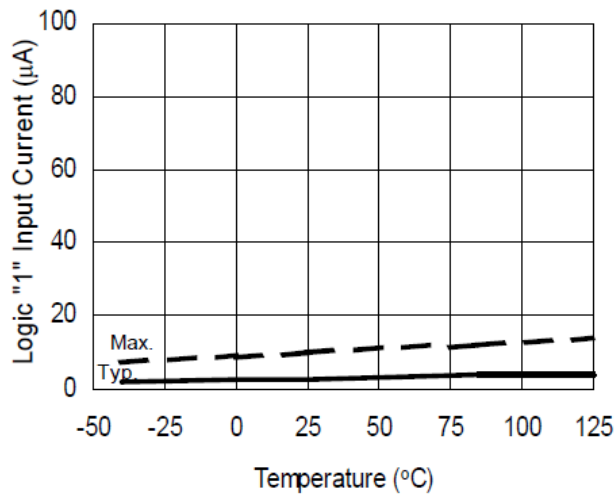
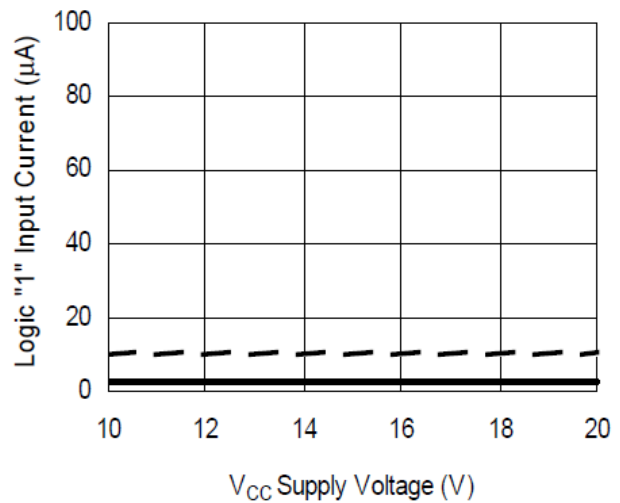
**Figure 12B. Offset Supply Leakage Current vs. Supply Voltage**

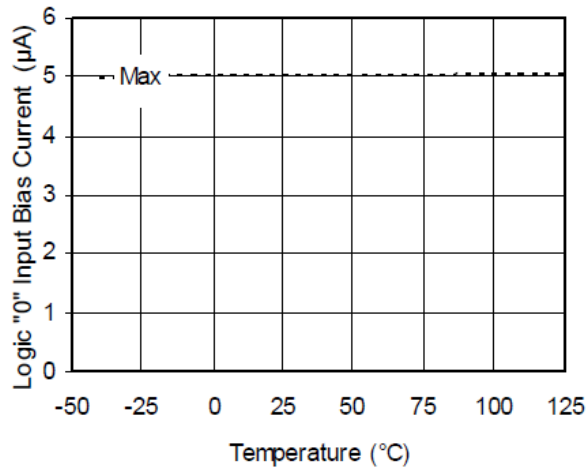


**Figure 13A.  $V_{BS}$  Supply Current vs. Temperature**

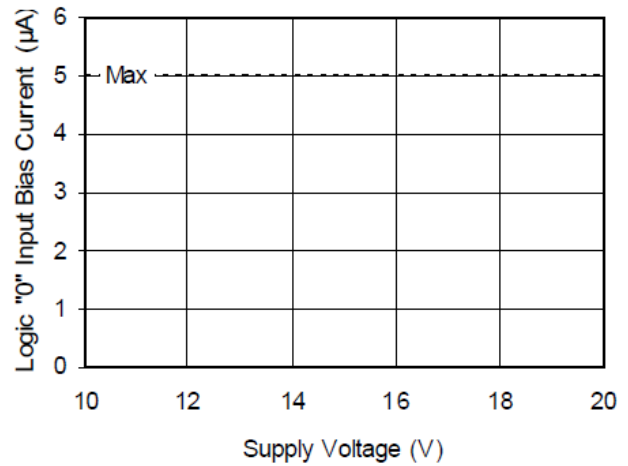


**Figure 13B.  $V_{BS}$  Supply Current vs. Supply Voltage**

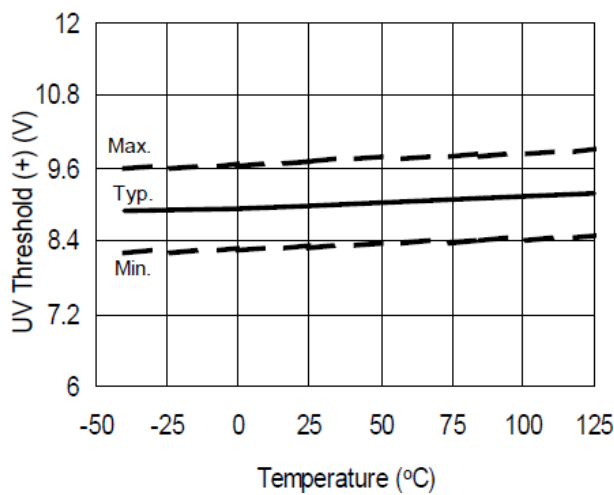

**Figure 14A.  $V_{CC}$  Supply Current vs. Temperature**

**Figure 14B.  $V_{CC}$  Supply Current vs. Supply Voltage**

**Figure 15A. Logic "1" Input Current vs. Temperature**

**Figure 15 B. Logic "1" Input Current vs. Supply Voltage**



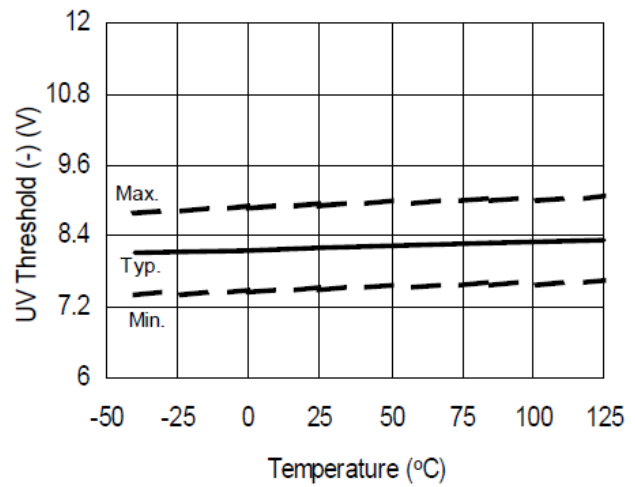
**Figure 16A. Logic "0" Input Bias Current vs. Temperature**



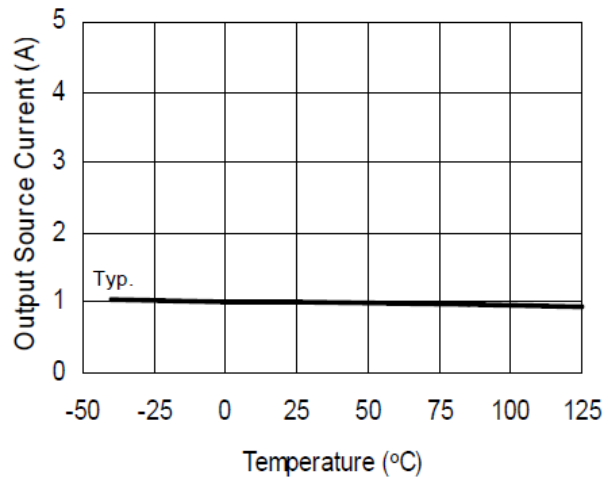
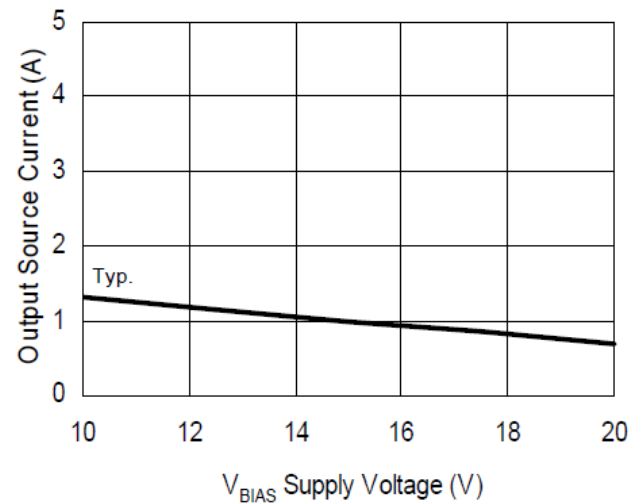
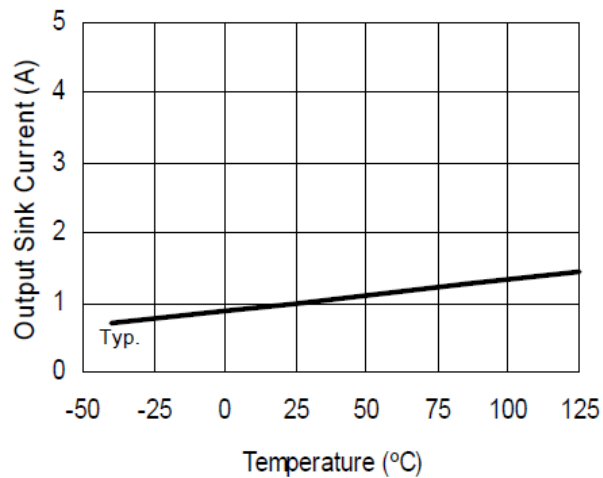
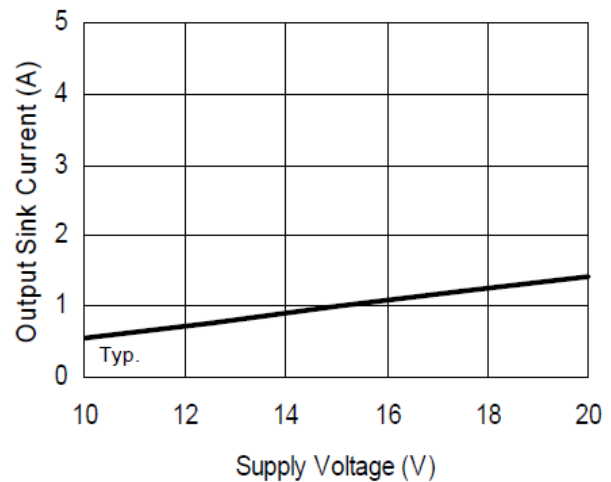
**Figure 16B. Logic "0" Input Bias Current vs. Voltage**

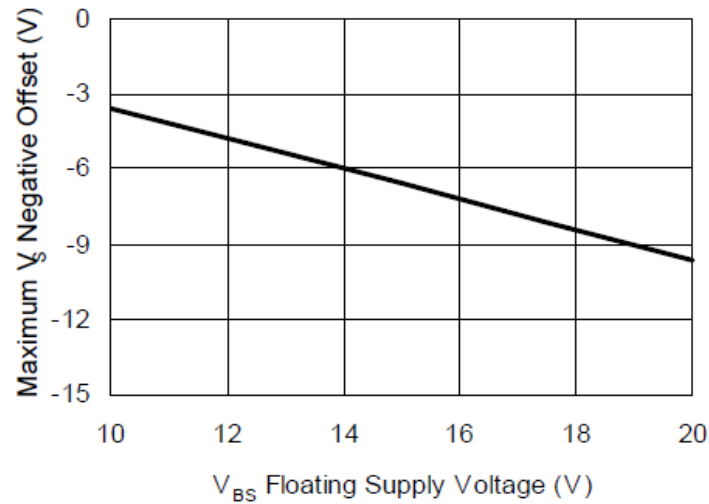


**Figure 17.  $V_{CC}$  and  $V_{BS}$  Undervoltage Threshold (+) vs. Temperature**

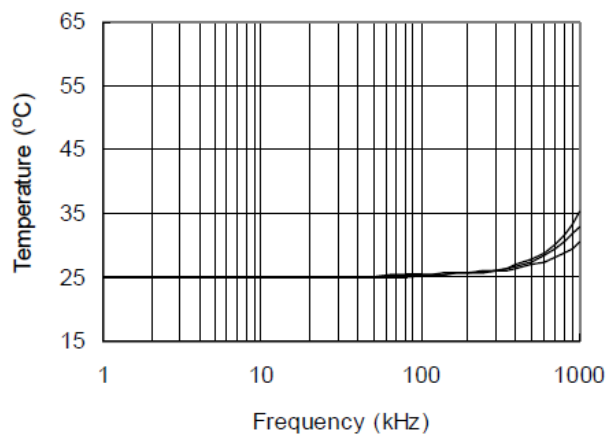


**Figure 18.  $V_{CC}$  and  $V_{BS}$  Undervoltage Threshold (-) vs. Temperature**

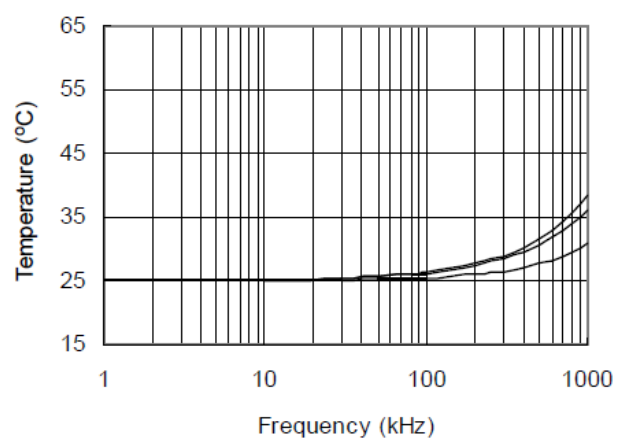

**Figure 19A. Output Source Current vs. Temperature**

**Figure 19B. Output Source Current vs. Supply Voltage**

**Figure 20A. Output Sink Current vs. Temperature**

**Figure 20B. Output Sink Currnt vs. Supply Voltage**



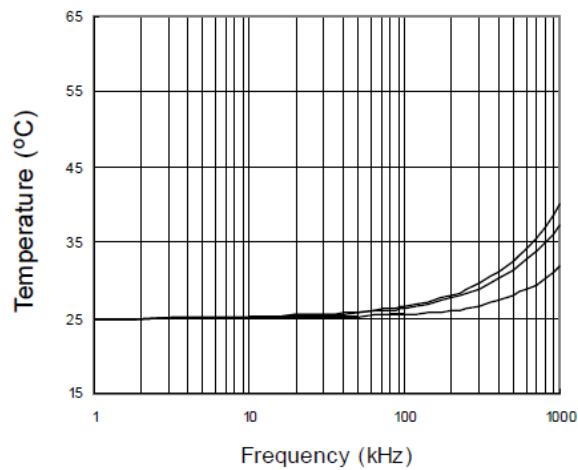
**Figure 21. Maximum  $V_S$  Negative Offset vs.  $V_{BS}$  Floating Supply Voltage**



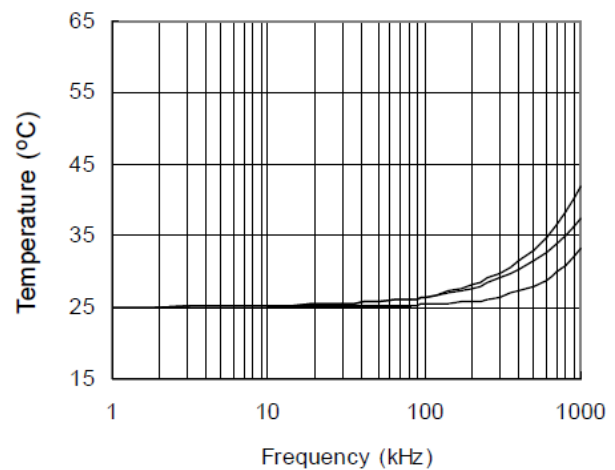
**Figure 22. IRS2011S vs. Frequency (IRFBC20)**  
 $R_{gate} = 33\Omega$ ,  $V_{CC} = 12V$



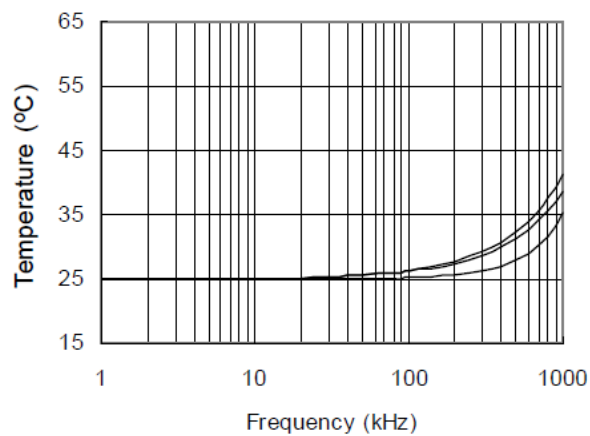
**Figure 23. IRS2011S vs. Frequency (IRFB30)**  
 $R_{gate} = 22\Omega$ ,  $V_{CC} = 12V$



**Figure 24. IRS2011S vs. Frequency (IRFBC40)**  
 $R_{gate} = 15\Omega$ ,  $V_{CC} = 12V$

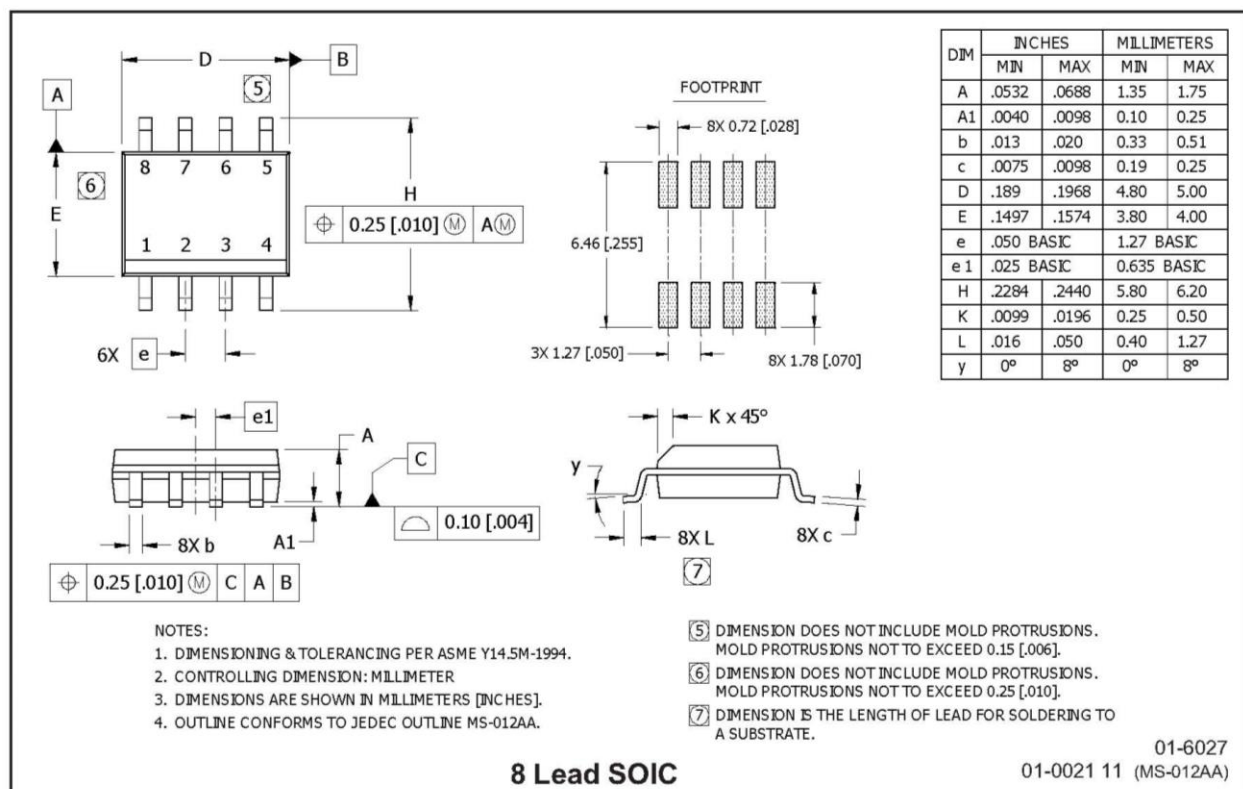
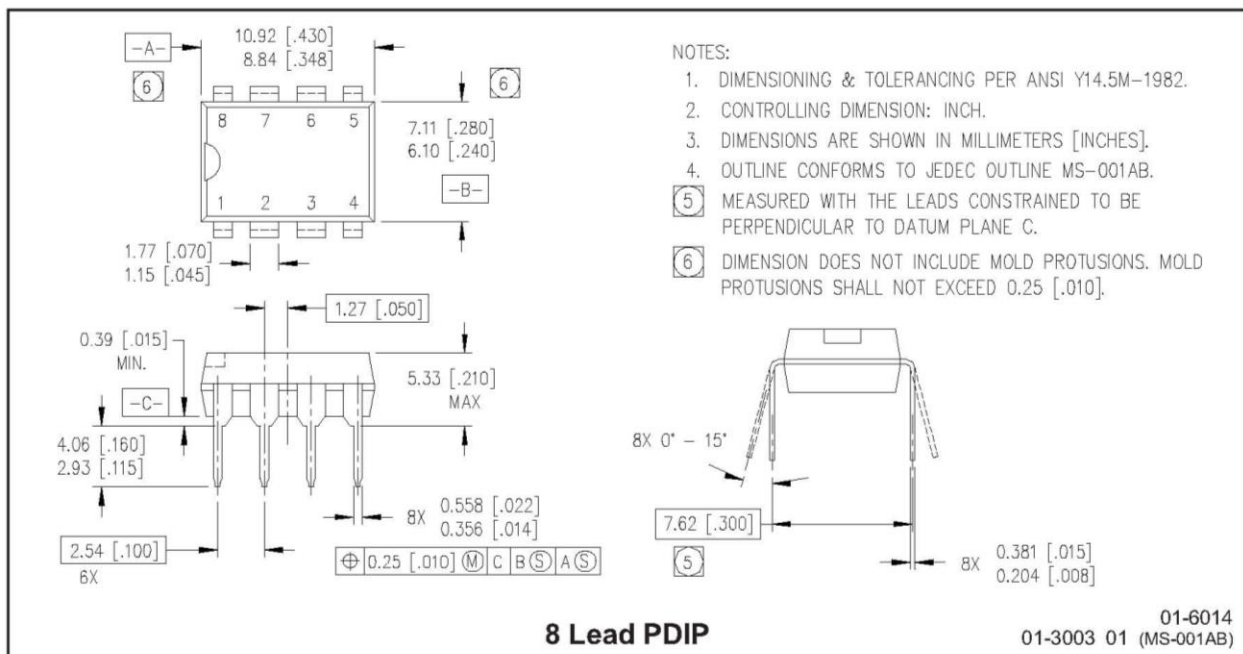


**Figure 25. IRS2011S vs. Frequency (IRFB23N15D)**  
 $R_{gate} = 10\Omega$ ,  $V_{CC} = 12V$

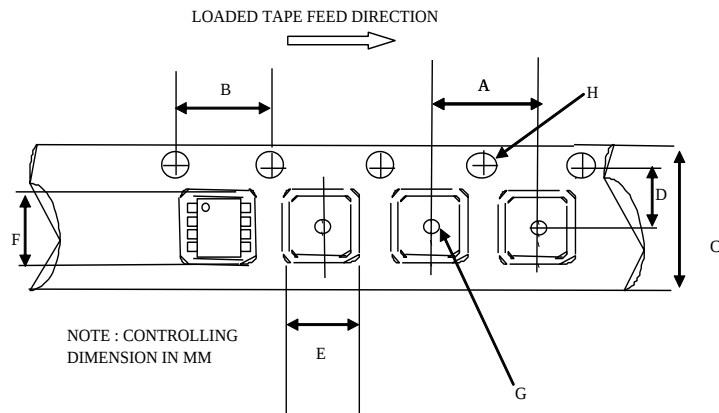


**Figure 26. IRS2011S vs. Frequency (IRFB4212)**  
 $R_{gate} = 10\Omega$ ,  $V_{CC} = 12V$

## Package Details

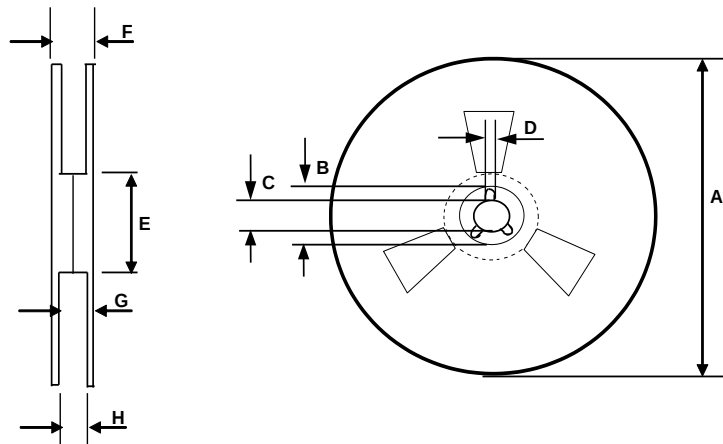


## Tape and Reel Details



CARRIER TAPE DIMENSION FOR 8SOICN

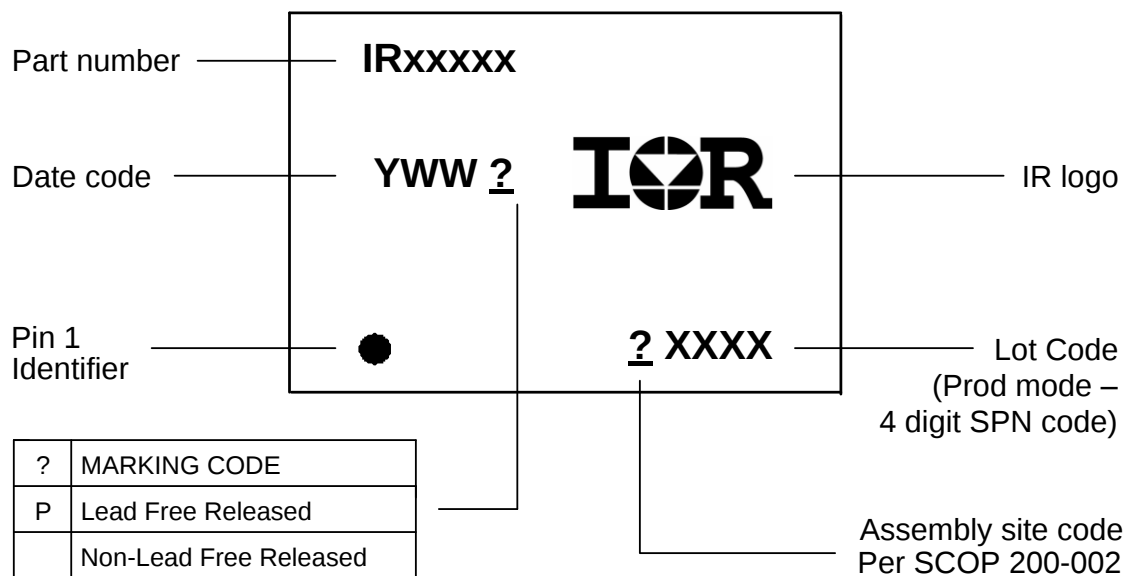
| Code | Metric |       | Imperial |       |
|------|--------|-------|----------|-------|
|      | Min    | Max   | Min      | Max   |
| A    | 7.90   | 8.10  | 0.311    | 0.318 |
| B    | 3.90   | 4.10  | 0.153    | 0.161 |
| C    | 11.70  | 12.30 | 0.46     | 0.484 |
| D    | 5.45   | 5.55  | 0.214    | 0.218 |
| E    | 6.30   | 6.50  | 0.248    | 0.255 |
| F    | 5.10   | 5.30  | 0.200    | 0.208 |
| G    | 1.50   | n/a   | 0.059    | n/a   |
| H    | 1.50   | 1.60  | 0.059    | 0.062 |



REEL DIMENSIONS FOR 8SOICN

| Code | Metric |        | Imperial |        |
|------|--------|--------|----------|--------|
|      | Min    | Max    | Min      | Max    |
| A    | 329.60 | 330.25 | 12.976   | 13.001 |
| B    | 20.95  | 21.45  | 0.824    | 0.844  |
| C    | 12.80  | 13.20  | 0.503    | 0.519  |
| D    | 1.95   | 2.45   | 0.767    | 0.096  |
| E    | 98.00  | 102.00 | 3.858    | 4.015  |
| F    | n/a    | 18.40  | n/a      | 0.724  |
| G    | 14.50  | 17.10  | 0.570    | 0.673  |
| H    | 12.40  | 14.40  | 0.488    | 0.566  |

## Part Marking Information



## Qualification Information<sup>†</sup>

|                                   |             |                                                                                                                                                                     |
|-----------------------------------|-------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>Qualification Level</b>        |             | Industrial <sup>††</sup><br>(per JEDEC JESD 47)                                                                                                                     |
|                                   |             | Comments: This family of ICs has passed JEDEC's Industrial qualification. IR's Consumer qualification level is granted by extension of the higher Industrial level. |
| <b>Moisture Sensitivity Level</b> | 8-Lead SOIC | MSL2 <sup>†††</sup><br>(per IPC/JEDEC J-STD-020)                                                                                                                    |
| <b>RoHS Compliant</b>             |             | Yes                                                                                                                                                                 |

† Qualification standards can be found at International Rectifier's web site <http://www.irf.com/>

†† Higher qualification ratings may be available should the user have such requirements. Please contact your International Rectifier sales representative for further information.

††† Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.

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<http://www.irf.com/technical-info/>

**WORLD HEADQUARTERS:**  
 233 Kansas St., El Segundo, California 90245  
 Tel: (310) 252-7105